

**ANALOG
DEVICES**

Dual-Channel Ultralow Noise Amplifier with Selectable Gain and Input Impedance

AD8432

FEATURES

Low noise

Input voltage noise: 0.85 nV/ $\sqrt{\text{Hz}}$

Current noise: 2.0 pA/ $\sqrt{\text{Hz}}$

Excellent ac specifications

200 MHz bandwidth ($G = 12.04$ dB)

295 V/ μs slew rate

Selectable gain

$G = 12.04$ dB ($\times 4$)

$G = 18.06$ dB ($\times 8$)

$G = 21.58$ dB ($\times 12$)

$G = 24.08$ dB ($\times 16$)

Active input impedance matching

Integrated input clamp diodes

Single-ended input, differential output

Supply range: 4.5 V to 5.5 V

Low power: 60 mW/channel

FUNCTIONAL BLOCK DIAGRAM

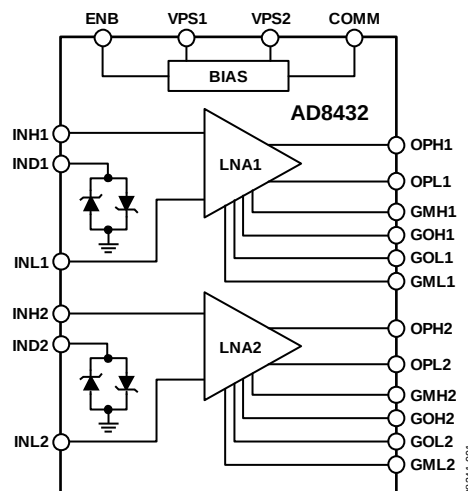


Figure 1.

APPLICATIONS

CW Doppler ultrasound front ends

Low noise preamplification

Predriver for I/Q demodulators and phase shifters

Wideband analog-to-digital drivers

GENERAL DESCRIPTION

The AD8432 is a dual-channel, low power, ultralow noise amplifier with selectable gain and active impedance matching. Each amplifier has a single-ended input, differential output, and integrated input clamps. By pin strapping the gain setting pins, four accurate gains of $G = 12.04$ dB, 18.06 dB, 21.58 dB, and 24.08 dB ($\times 4$, $\times 8$, $\times 12$, and $\times 16$) are possible. A bandwidth of 200 MHz at $G = 12.04$ dB makes this amplifier well suited for many high speed applications.

The exceptional noise performance of the AD8432 is made possible by the active impedance matching. Using a feedback network, the input impedance of the amplifiers can be adjusted to match the signal source impedance without compromising the noise performance. Impedance matching and low noise of the AD8432 allow designers to create wider dynamic range systems that are able to detect even very low level signals.

The AD8432 achieves 0.85 nV/ $\sqrt{\text{Hz}}$ input referred voltage noise for a gain of 12.04 dB. The AD8432's ultralow noise, low distortion, excellent gain accuracy, and channel-to-channel matching are ideal for high performance ultrasound systems and for processing I/Q demodulator signals.

The AD8432 operates on a single supply of 5 V at 24 mA. It is available in a 4 mm $\times$ 4 mm, 24-lead LFSCSP. The LFSCSP features an exposed paddle that provides a low thermal resistance path to the PCB, which enables more efficient heat transfer and increases reliability. The operating temperature range is -40°C to $+85^{\circ}\text{C}$.

Rev. 0

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REVISION HISTORY

10/09—Revision 0: Initial Version

SPECIFICATIONS

$V_S = 5\text{ V}$, $T_A = 25^\circ\text{C}$, $R_S = R_{IN} = 50\ \Omega$, $R_{FB} = 150\ \Omega$, $C_{SH} = 47\text{ pF}$, $R_{SH} = 15\ \Omega$, $R_L = 500\ \Omega$ (per SE output), $C_L = 5\text{ pF}$ (per SE output), $G = 12.04\text{ dB}$ (single-ended input to differential output), $f = 1\text{ MHz}$, unless otherwise specified.

Table 1.

Parameter	Conditions	Min	Typ	Max	Unit
DYNAMIC PERFORMANCE					
Gain Range	Input to differential output (selectable gain)	12.04		24.08	dB
	Input to single output (selectable gain)	6.02		18.06	dB
Gain Error			0.1	1	dB
–3 dB Small Signal Bandwidth	R_{IN} unterminated, $R_{FB} = \infty$, $C_{SH} = 0\text{ pF}$, $R_{SH} = 0\ \Omega$				
	$G = 12.04\text{ dB}$		200		MHz
	$G = 18.06\text{ dB}$		90		MHz
	$G = 21.58\text{ dB}$		50		MHz
	$G = 24.08\text{ dB}$		32		MHz
–3 dB Large Signal Bandwidth	$V_{OUT} = 2\text{ V p-p}$		42		MHz
Slew Rate (Rising Edge)	$V_{OUT} = 2\text{ V p-p}$, $f = 10\text{ MHz}$		295		V/ μs
Slew Rate (Falling Edge)	$V_{OUT} = 2\text{ V p-p}$, $f = 10\text{ MHz}$		170		V/ μs
Overdrive Recovery Time			10		ns
DISTORTION/NOISE PERFORMANCE					
Input Voltage Noise	$R_{FB} = \infty$		0.85		nV/ $\sqrt{\text{Hz}}$
Input Current Noise	$R_{FB} = \infty$		2.0		pA/ $\sqrt{\text{Hz}}$
Noise Figure					
Unterminated	$R_S = 50\ \Omega$, $R_{FB} = \infty$		2.8		dB
Active Termination	$R_S = R_{IN} = 50\ \Omega$, $R_{FB} = 150\ \Omega$		4.8		dB
	$R_S = 50\ \Omega$, $R_{FB} = 226\ \Omega$, $R_{IN} = 75\ \Omega$		4.2		dB
	$R_S = 50\ \Omega$, $R_{FB} = 301\ \Omega$, $R_{IN} = 100\ \Omega$		3.2		dB
	$R_S = 50\ \Omega$, $R_{FB} = 619\ \Omega$, $R_{IN} = 200\ \Omega$		2.1		dB
	$R_S = 50\ \Omega$, $R_{FB} = 3.57\text{ k}\Omega$, $R_{IN} = 1\text{ k}\Omega$		2.3		dB
Output Referred Noise	$G = 12.04\text{ dB}$, $R_{FB} = \infty$		3.4		nV/ $\sqrt{\text{Hz}}$
	$G = 18.06\text{ dB}$, $R_{FB} = \infty$		6.8		nV/ $\sqrt{\text{Hz}}$
	$G = 21.58\text{ dB}$, $R_{FB} = \infty$		10.2		nV/ $\sqrt{\text{Hz}}$
	$G = 24.08\text{ dB}$, $R_{FB} = \infty$		13.6		nV/ $\sqrt{\text{Hz}}$
Harmonic Distortion					
1 MHz ($V_{OUT} = 1\text{ V p-p}$)	HD2		–67		dBc
	HD2, $R_S = 50\ \Omega$, R_{IN} unterminated		–74		dBc
	HD3		–103		dBc
	HD3, $R_S = 50\ \Omega$, R_{IN} unterminated		–106		dBc
1 MHz ($V_{OUT} = 2\text{ V p-p}$)	HD2		–65		dBc
	HD2, $R_S = 50\ \Omega$, R_{IN} unterminated		–72		dBc
	HD3		–103		dBc
	HD3, $R_S = 50\ \Omega$, R_{IN} unterminated		–92		dBc
10 MHz ($V_{OUT} = 1\text{ V p-p}$)	HD2		–66		dBc
	HD2, $R_S = 50\ \Omega$, R_{IN} unterminated		–62		dBc
	HD3		–78		dBc
	HD3, $R_S = 50\ \Omega$, R_{IN} unterminated		–73		dBc
10 MHz ($V_{OUT} = 2\text{ V p-p}$)	HD2		–60		dBc
	HD2, $R_S = 50\ \Omega$, R_{IN} unterminated		–56		dBc
	HD3		–72		dBc
	HD3, $R_S = 50\ \Omega$, R_{IN} unterminated		–65		dBc

AD8432

Parameter	Conditions	Min	Typ	Max	Unit
Two-Tone IMD3 Distortion	$R_S = 50\ \Omega$, R_{IN} unterminated				
10 MHz	$V_{OUT} = 1\text{ V p-p}$, $f_1 = 9.5\text{ MHz}$, $f_2 = 10.5\text{ MHz}$		–89.1		dBc
	$V_{OUT} = 2\text{ V p-p}$, $f_1 = 9.5\text{ MHz}$, $f_2 = 10.5\text{ MHz}$		–66.0		dBc
1 MHz	$V_{OUT} = 1\text{ V p-p}$, $f_1 = 0.9\text{ MHz}$, $f_2 = 1.1\text{ MHz}$		–88.9		dBc
	$V_{OUT} = 2\text{ V p-p}$, $f_1 = 0.9\text{ MHz}$, $f_2 = 1.1\text{ MHz}$		–73.7		dBc
Input 1dB Compression Point	$f = 1\text{ MHz}$		7.5		dBm
	$f = 10\text{ MHz}$		7.7		dBm
Output Third-Order Intercept					
1 MHz	$V_{OUT} = 1\text{ V p-p}$ of composite tones		29.7		dBV rms
	$V_{OUT} = 2\text{ V p-p}$ of composite tones		28.2		dBV rms
10 MHz	$V_{OUT} = 1\text{ V p-p}$ of composite tones		23.2		dBV rms
	$V_{OUT} = 2\text{ V p-p}$ of composite tones		24.2		dBV rms
1 MHz	$V_{OUT} = 1\text{ V p-p}$ of composite tones, reference to $50\ \Omega$		42.7		dBm
	$V_{OUT} = 2\text{ V p-p}$ of composite tones, reference to $50\ \Omega$		41.2		dBm
10 MHz	$V_{OUT} = 1\text{ V p-p}$ of composite tones, reference to $50\ \Omega$		36.2		dBm
	$V_{OUT} = 2\text{ V p-p}$ of composite tones, reference to $50\ \Omega$		37.2		dBm
Crosstalk	$V_{OUT} = 1\text{ V p-p}$, $f = 1\text{ MHz}$		102		dB
DC PERFORMANCE					
Input Offset Voltage		–6.25	+1	+6.25	mV
Input Offset Voltage Drift			300		$\mu\text{V}/^\circ\text{C}$
INPUT CHARACTERISTICS					
Input Voltage Range	AC-coupled		1.2		V p-p
Input Resistance	$R_{FB} = 150\ \Omega$		50		Ω
	$R_{FB} = 226\ \Omega$		75		Ω
	$R_{FB} = 301\ \Omega$		100		Ω
	$R_{FB} = 619\ \Omega$		200		Ω
	$R_{FB} = 3.57\text{ k}\Omega$		1		k Ω
	$R_{FB} = \infty$, $f = 100\text{ kHz}$		6.2		k Ω
Input Capacitance			6		pF
Input Common Mode Voltage			3.25		V
OUTPUT CHARACTERISTICS					
Output Common-Mode Voltage			2.5		V
Output Offset Voltage		–25	+4	+25	mV
Output Voltage Swing			4.8		V p-p
Output Resistance	Single-ended, either output		<0.1		Ω
Output Resistance in Shutdown Mode	Single-ended, either output		2.5		k Ω
Output Short-Circuit Current	$R_L = 10\ \Omega$ differential		77		mA
Enable Response Time	ENB _{ON} (enable high to output on)		200		μs
	ENB _{OFF} (enable low to output off)		200		μs
POWER SUPPLY					
Supply Voltage		4.5	5	5.5	V
Quiescent Current	All channels enabled		24		mA
Over Temperature	$T_A = -40^\circ\text{C}$		21		mA
	$T_A = +85^\circ\text{C}$		27		mA
Supply Current in Shutdown Mode	ENB = GND		50	100	μA
Power Dissipation			120		mW
PSRR	$G = 24.08\text{ dB}$, $f = 100\text{ kHz}$, no bypass capacitors		–82		dB

ABSOLUTE MAXIMUM RATINGS

Table 2.

Parameter	Rating
Voltage	
Supply Voltage	5.5 V
Input Voltage	0 V to VPS
Power Dissipation	120 mW
Temperature	
Operating Temperature	–40°C to +85°C
Storage Temperature	–65°C to +150°C
Package Glass Transition Temperature (T _G)	150°C
Lead Temperature (Soldering, 60 sec)	300°C

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

THERMAL RESISTANCE

θ_{JA} is specified for the worst-case conditions, that is, a device soldered in a circuit board for surface-mount packages. The θ_{JA} values in Table 3 assume a 4-layer JEDEC standard board with zero airflow.

Table 3. Thermal Resistance¹

Parameter	θ_{JA}	θ_{JC}	θ_{JB}	Ψ_{JT}	Unit
40-Lead LFCSP	57.9	11.2	35.9	1.1	°C/W

¹ 4-Layer JEDEC board (2S2P).

MAXIMUM POWER DISSIPATION

The maximum safe power dissipation for the AD8432 is limited by the associated rise in junction temperature (T_J) on the die. At approximately 150°C, which is the glass transition temperature, the properties of the plastic change. Even temporarily exceeding this temperature limit may change the stresses that the package exerts on the die, permanently shifting the parametric performance of the amplifiers. Exceeding a temperature of 150°C for an extended period can cause changes in silicon devices, potentially resulting in a loss of functionality.

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

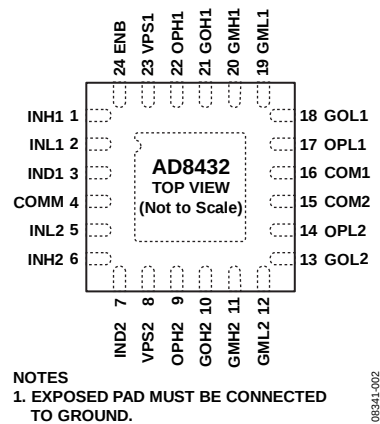


Figure 2. Pin Configuration

Table 4. Pin Function Descriptions

Pin No.	Mnemonic	Description
1	INH1	LNA1 Noninverting Input.
2	INL1	LNA1 Inverting Input (AC-Coupled to Ground).
3, 7	IND1, IND2	Integrated Input Clamping Back-to-Back Diodes.
4	COMM	Input Ground.
5	INL2	LNA2 Inverting Input (AC-Coupled to Ground).
6	INH2	LNA2 Noninverting Input.
8	VPS2	5 V Supply for LNA2.
9	OPH2	Noninverting Output of LNA2.
10	GOH2	Gain Setting Pin for LNA2.
11	GMH2	Gain Setting Pin for LNA2.
12	GML2	Gain Setting Pin for LNA2.
13	GOL2	Gain Setting Pin for LNA2.
14	OPL2	Inverting Output of LNA2.
15	COM2	LNA2 Output Ground.
16	COM1	LNA1 Output Ground.
17	OPL1	Inverting Output of LNA1.
18	GOL1	Gain Setting Pin for LNA1.
19	GML1	Gain Setting Pin for LNA1.
20	GMH1	Gain Setting Pin for LNA1.
21	GOH1	Gain Setting Pin for LNA1.
22	OPH1	Noninverting Output of LNA1.
23	VPS1	5 V Supply of LNA1 .
24	ENB	Enable.
	EPAD	Exposed pad must be connected to ground.

TYPICAL PERFORMANCE CHARACTERISTICS

$V_S = 5\text{ V}$, $T_A = 25^\circ\text{C}$, $R_S = R_{IN} = 50\ \Omega$, $R_{FB} = 150\ \Omega$, $C_{SH} = 47\text{ pF}$, $R_{SH} = 15\ \Omega$, $R_L = 500\ \Omega$ (per SE output), $C_L = 5\text{ pF}$ (per SE output), $G = 12.04\text{ dB}$ (single-ended input to differential output), $f = 1\text{ MHz}$, unless otherwise specified.

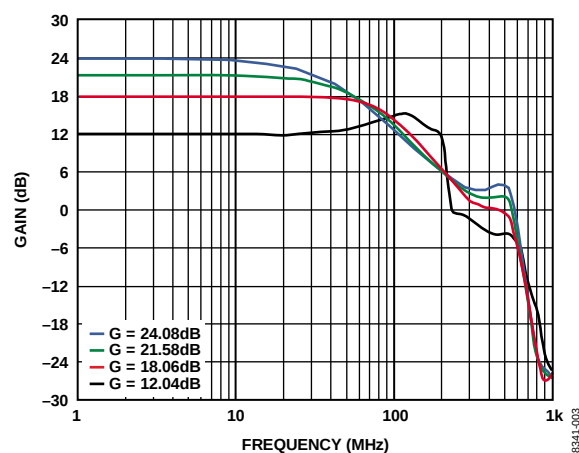


Figure 3. Small Signal Differential Gain vs. Frequency, R_{IN} Unterminated

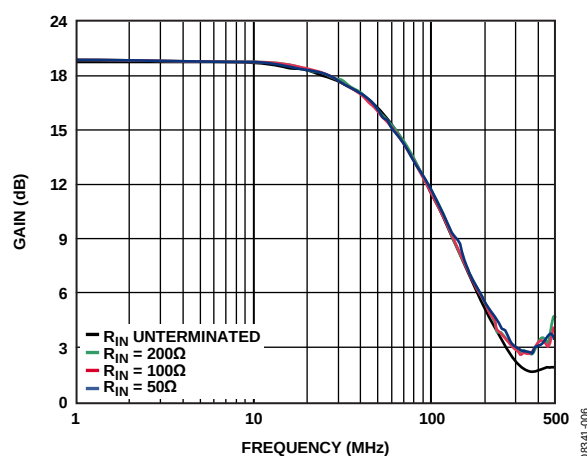


Figure 6. Small Signal Frequency Response vs. R_{IN} , $G = 21.58\text{ dB}$

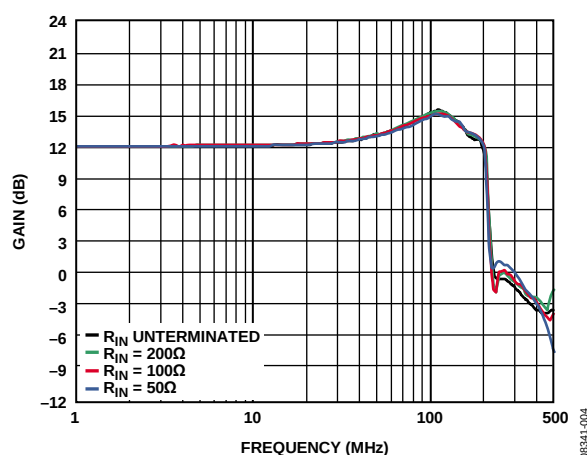


Figure 4. Small Signal Frequency Response vs. R_{IN} , $G = 12.04\text{ dB}$

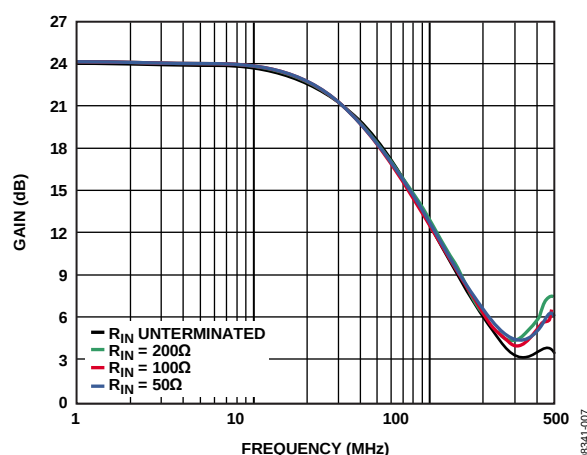


Figure 7. Small Signal Frequency Response vs. R_{IN} , $G = 24.08\text{ dB}$

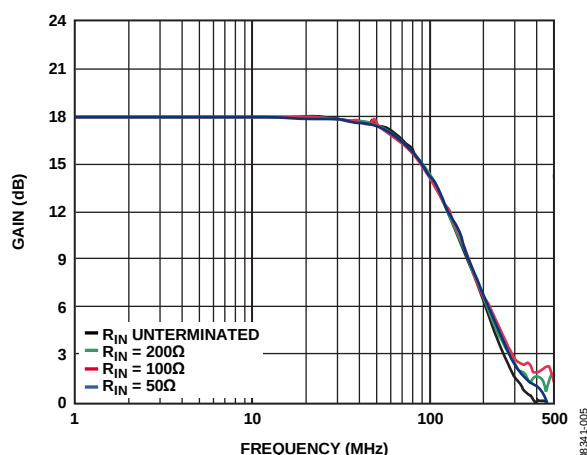


Figure 5. Small Signal Frequency Response vs. R_{IN} , $G = 18.06\text{ dB}$

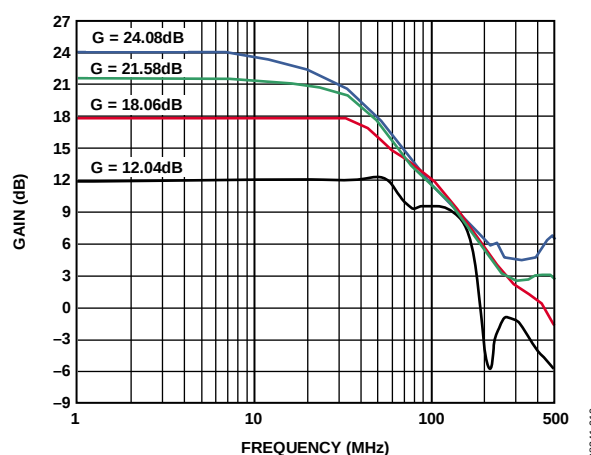


Figure 8. Differential Gain vs. Frequency, $V_{OUT} = 1\text{ V p-p}$, $R_{IN} = 50\ \Omega$

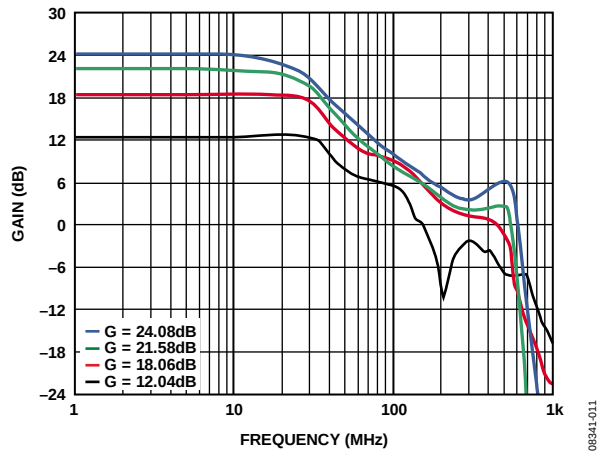


Figure 9. Differential Gain vs. Frequency, $V_{OUT} = 2\text{ V p-p}$, $R_{IN} = 50\Omega$

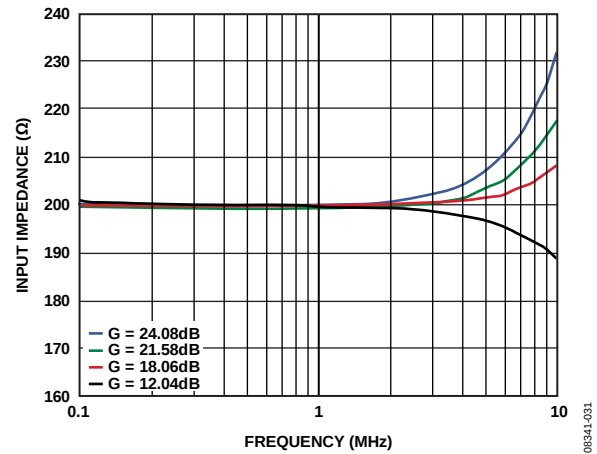


Figure 12. Input Impedance R_{IN} vs. Frequency, 200Ω Active Termination

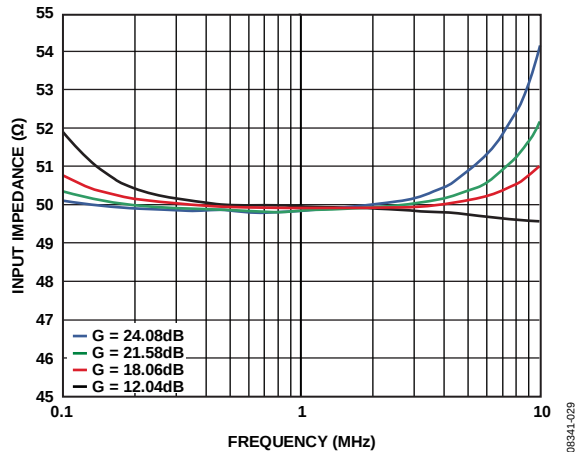


Figure 10. Input Impedance R_{IN} vs. Frequency, 50Ω Active Termination

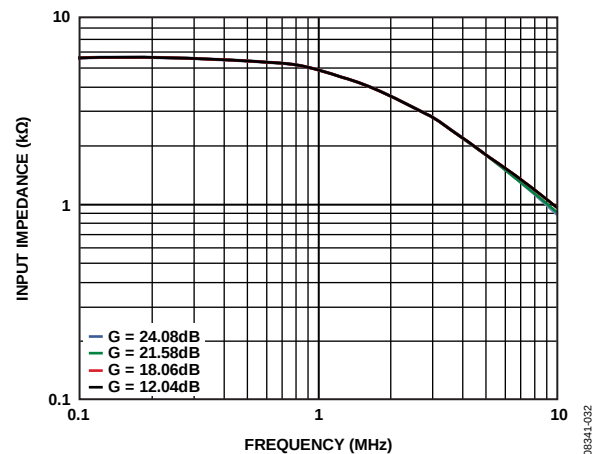


Figure 13. Input Impedance R_{IN} vs. Frequency, Unterminated

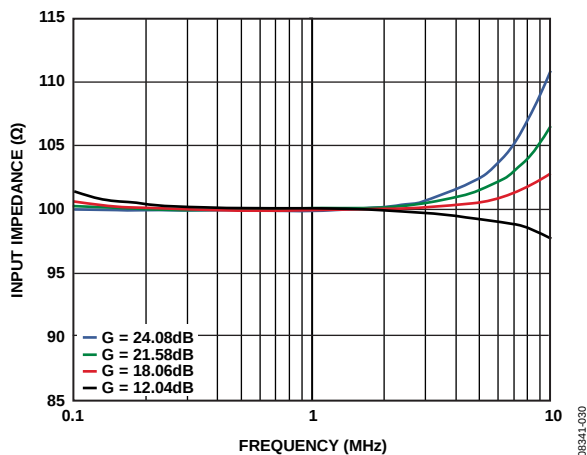


Figure 11. Input Impedance R_{IN} vs. Frequency, 100Ω Active Termination

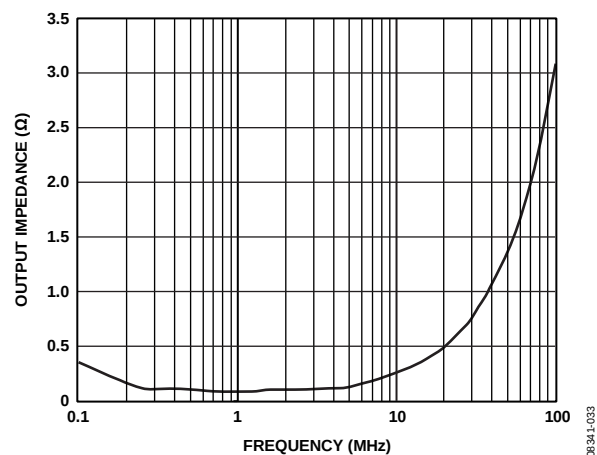


Figure 14. Output Impedance vs. Frequency

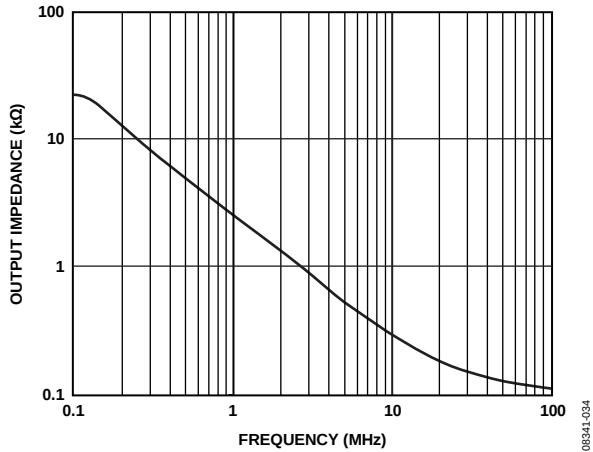


Figure 15. Output Impedance vs. Frequency in Disable Mode

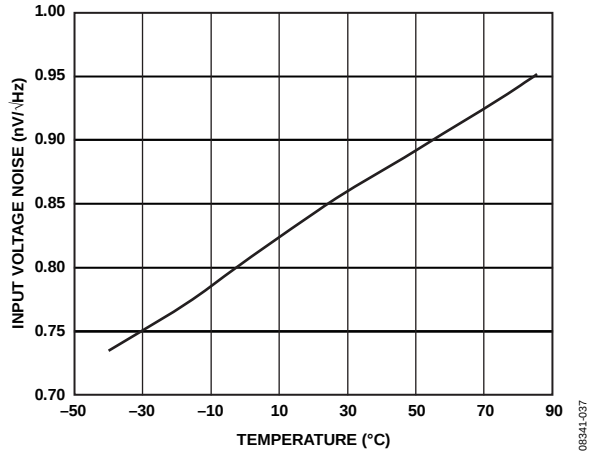


Figure 18. Input Voltage Noise vs. Temperature

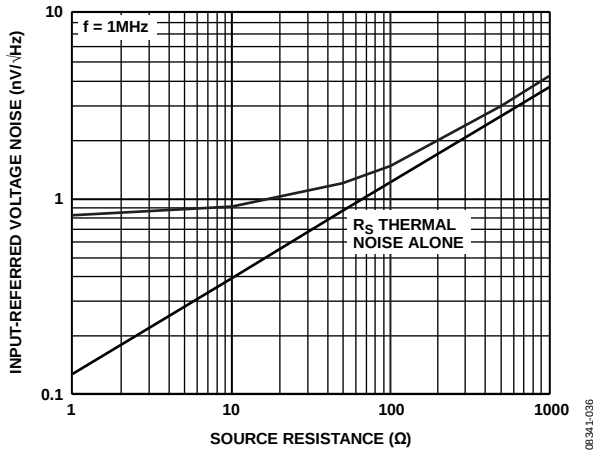


Figure 16. Input-Referred Voltage Noise vs. Source Resistance (R_S)

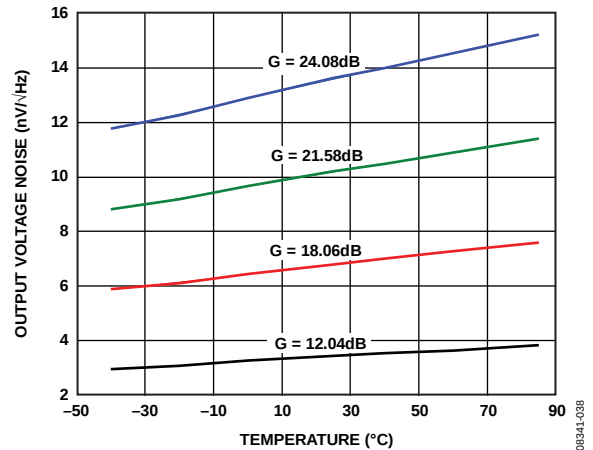


Figure 19. Output Voltage Noise vs. Temperature

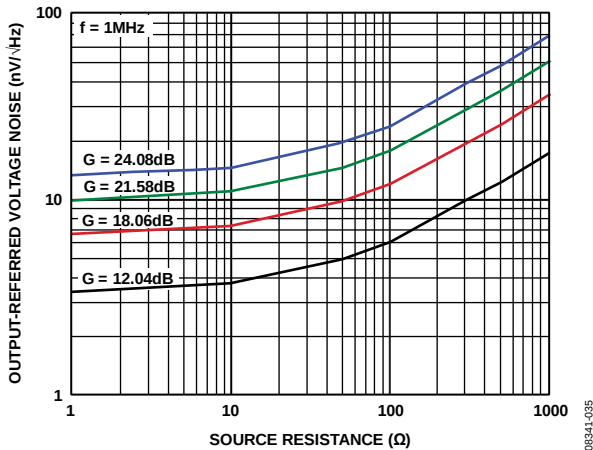


Figure 17. Output-Referred Voltage Noise vs. Source Resistance (R_S)

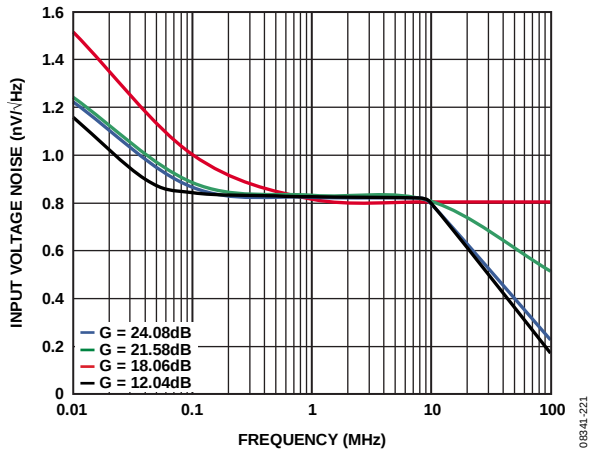


Figure 20. Input Voltage Noise vs. Frequency

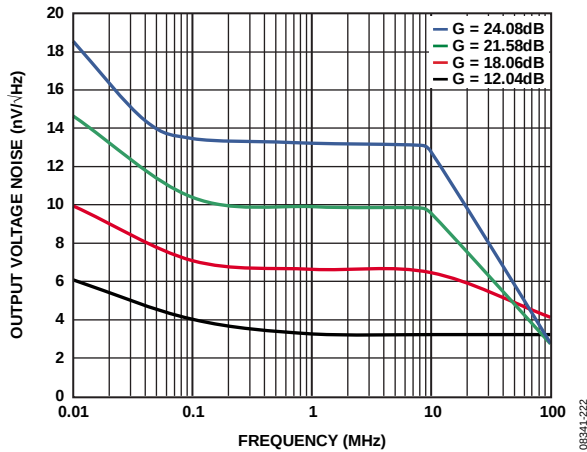


Figure 21. Output Voltage Noise vs. Frequency

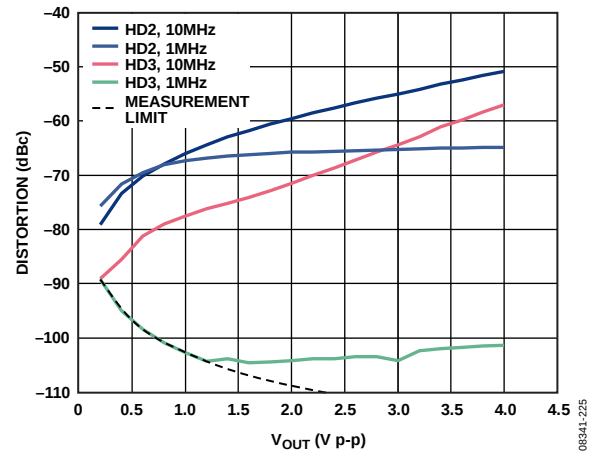
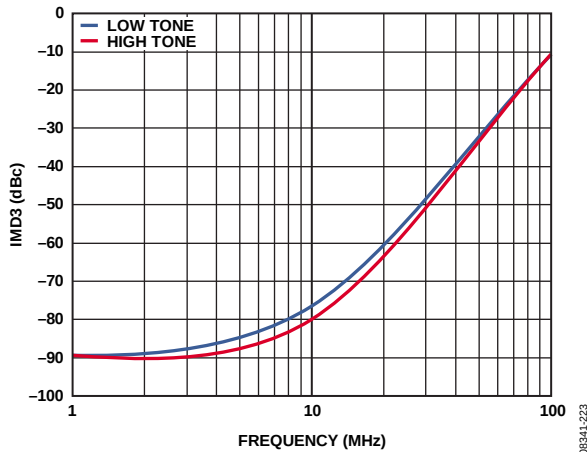
Figure 24. Harmonic Distortion vs. Differential Output Voltage, $G = 12.04$ dB

Figure 22. IMD3 vs. Frequency

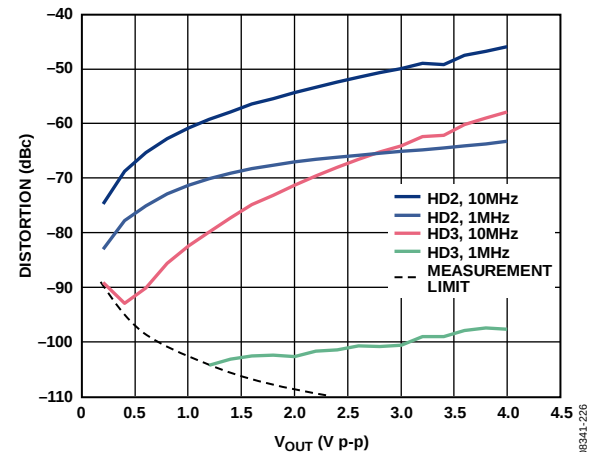
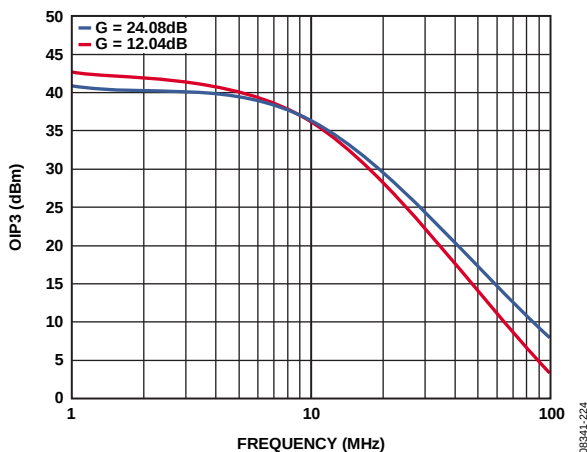
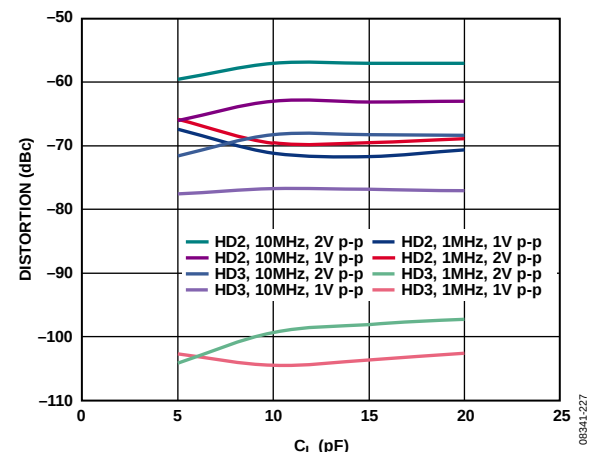
Figure 25. Harmonic Distortion vs. Differential Output Voltage, $G = 24.08$ dB

Figure 23. Output Third-Output Intercept vs. Frequency

Figure 26. Harmonic Distortion vs. Capacitive Load (C_L), $G = 12.04$ dB

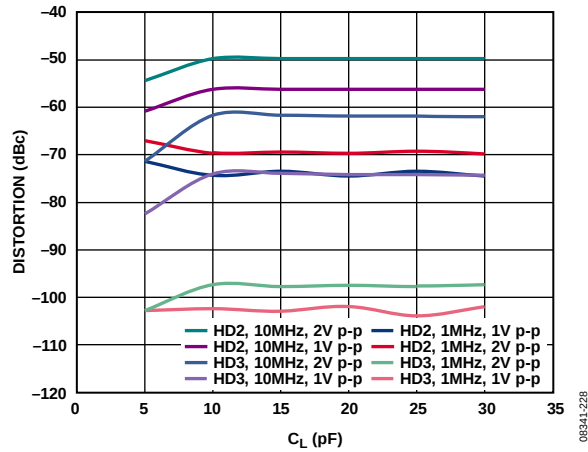
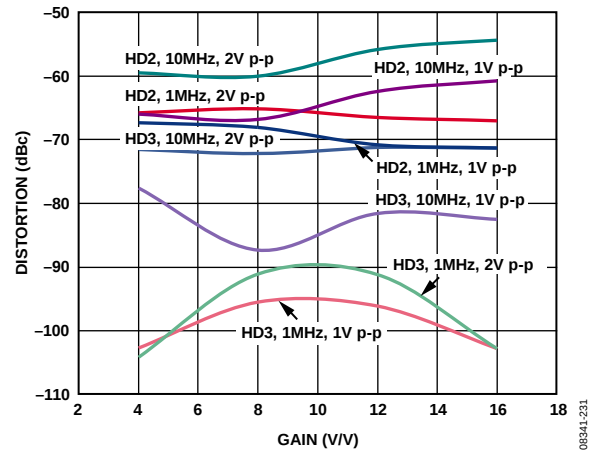
Figure 27. Harmonic Distortion vs. Capacitive Load (C_L), $G = 24.08$ dB

Figure 30. Harmonic Distortion vs. Gain

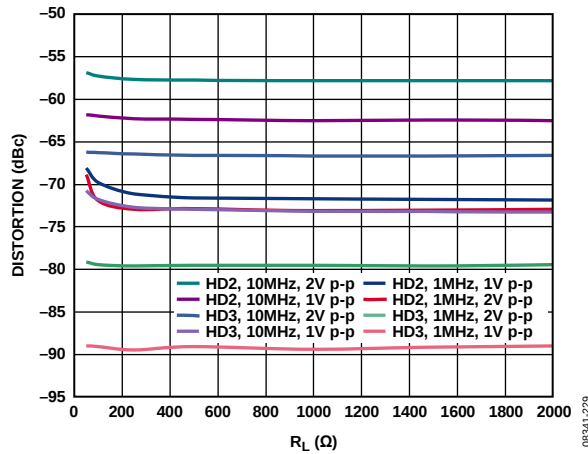
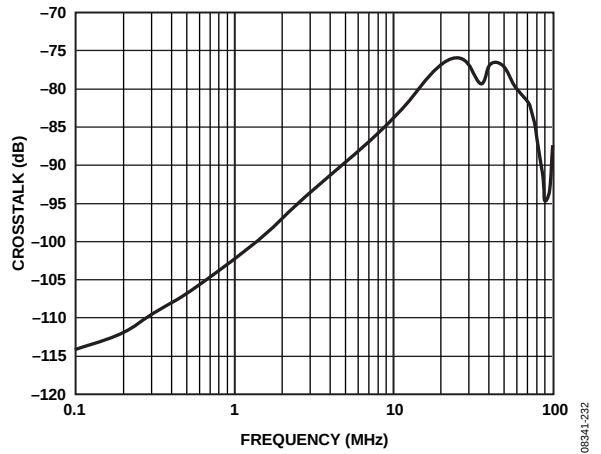
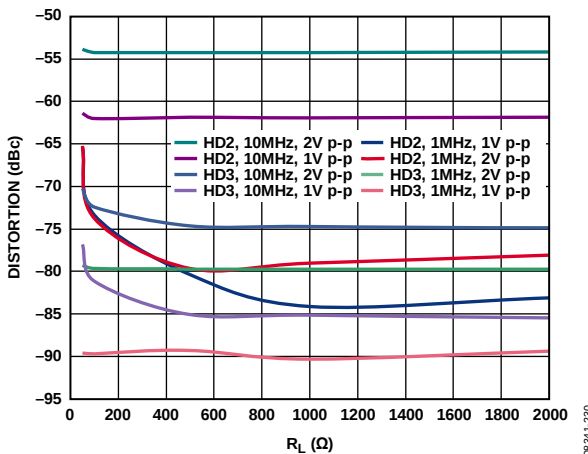
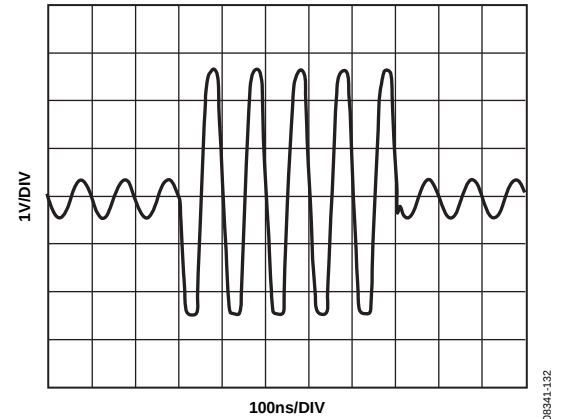
Figure 28. Harmonic Distortion vs. Resistive Load (R_L), $G = 12.04$ dB

Figure 31. Channel Crosstalk vs. Frequency

Figure 29. Harmonic Distortion vs. Resistive Load (R_L), $G = 24.08$ dBFigure 32. Overdrive Recovery, $G = 12.04$ dB

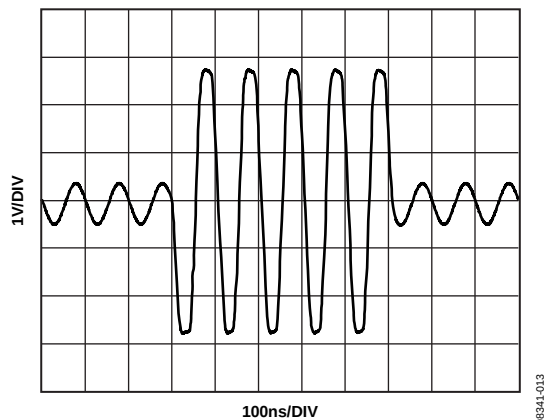


Figure 33. Overdrive Recovery, $G = 24.08$ dB

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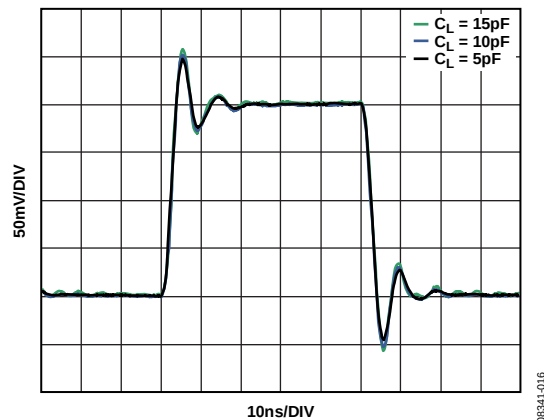


Figure 36. Small Signal Transient Response vs. Capacitive Load (C_L), $G = 12.04$ dB

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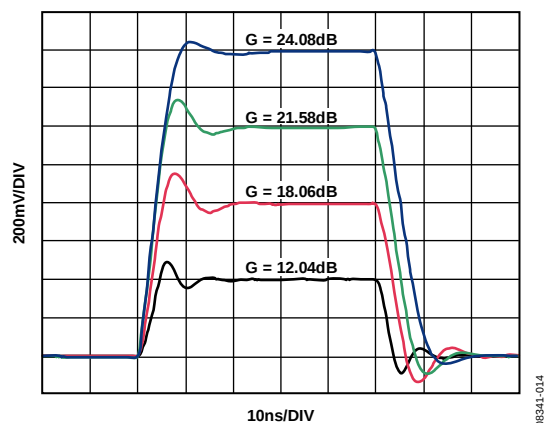


Figure 34. Small Signal Transient Response vs. Gain, $V_{IN} = 100$ mV p-p

08341-014

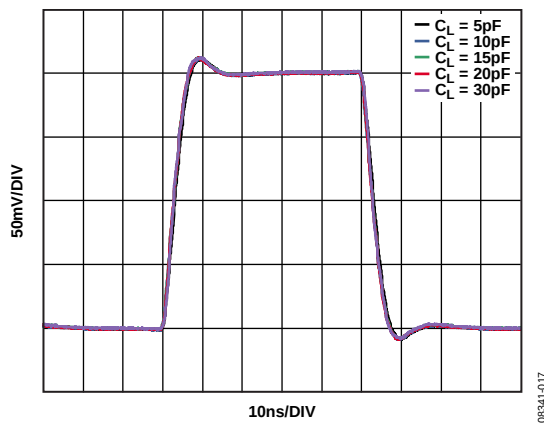


Figure 37. Small Signal Transient Response vs. Capacitive Load (C_L), $G = 24.08$ dB

08341-017



Figure 35. Small Signal Transient Response, $G = 12.04$ dB

08341-015

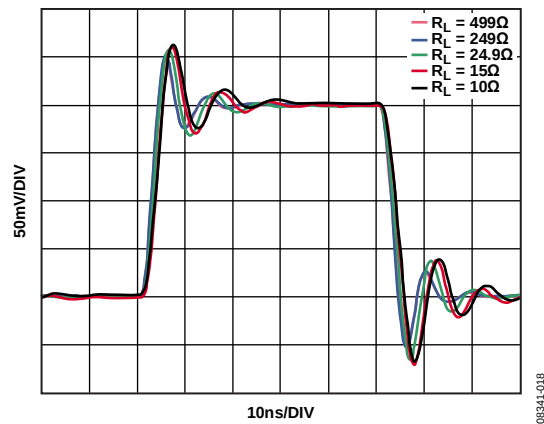
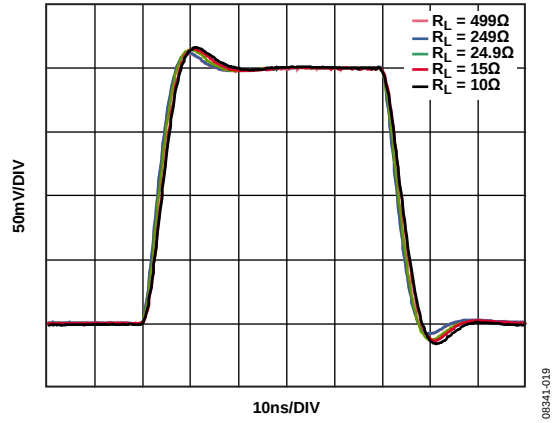
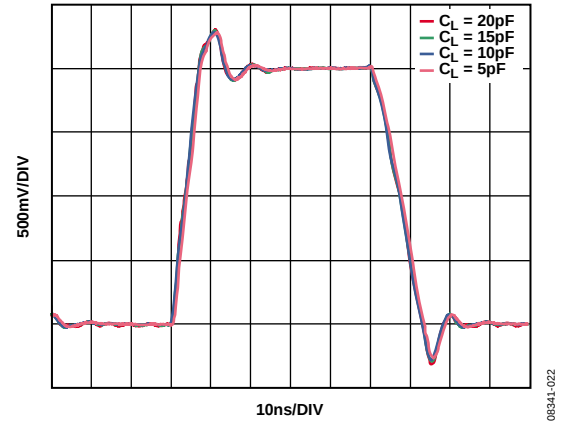
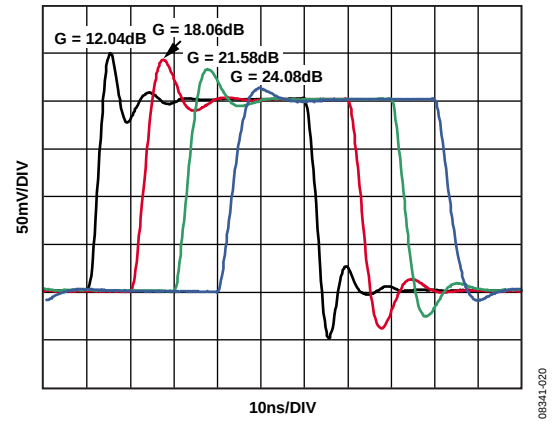
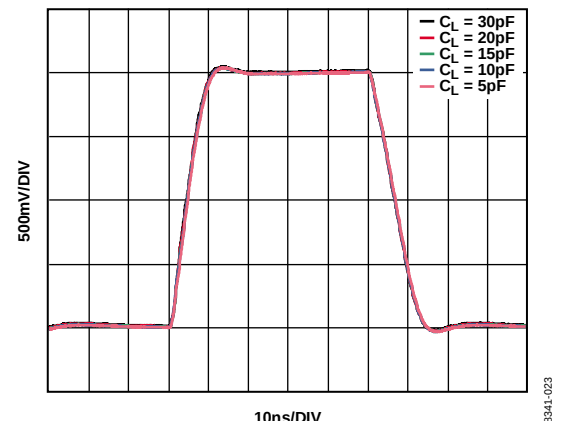
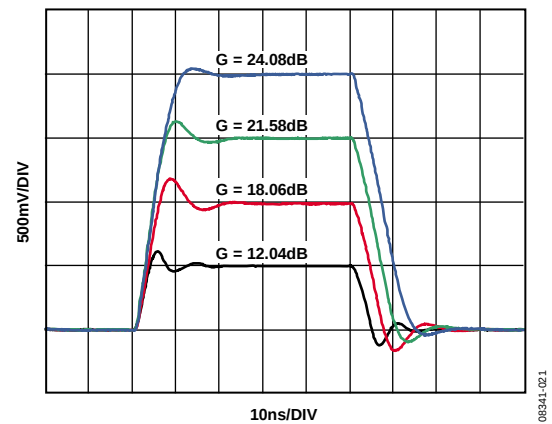
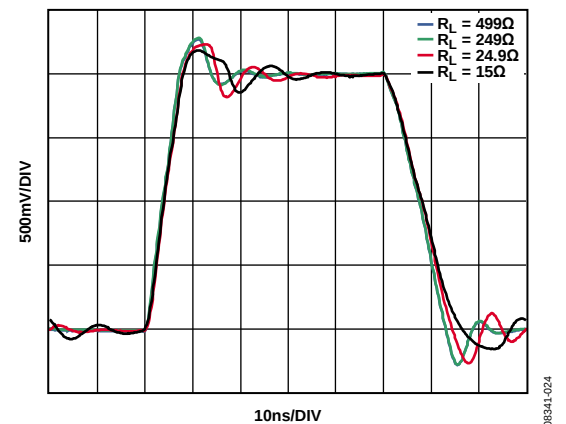


Figure 38. Small Signal Transient Response vs. Resistive Load (R_L), $G = 12.04$ dB

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Figure 39. Small Signal Transient Response vs. Resistive Load (R_L), $G = 24.08$ dBFigure 42. Large Signal Transient Response vs. Capacitive Load (C_L), $G = 12.04$ dBFigure 40. Small Signal Transient Response vs. Gain, $V_{OUT} = 200$ mV p-pFigure 43. Large Signal Transient Response vs. Capacitive Load (C_L), $G = 24.08$ dBFigure 41. Large Signal Transient Response vs. Gain, $V_{IN} = 125$ mV p-pFigure 44. Large Signal Transient Response vs. Resistive Load (R_L), $G = 12.04$ dB

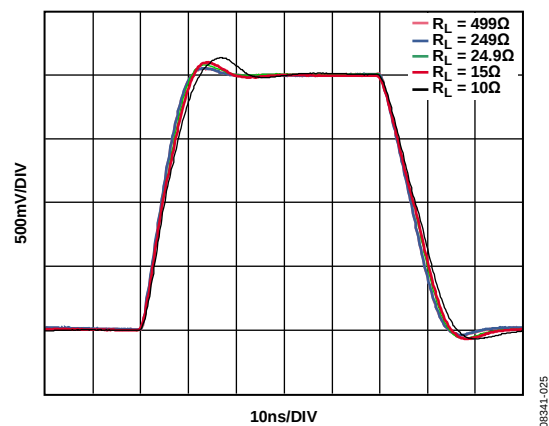


Figure 45. Large Signal Transient Response vs. Resistive Load (R_L), $G = 24.08$ dB

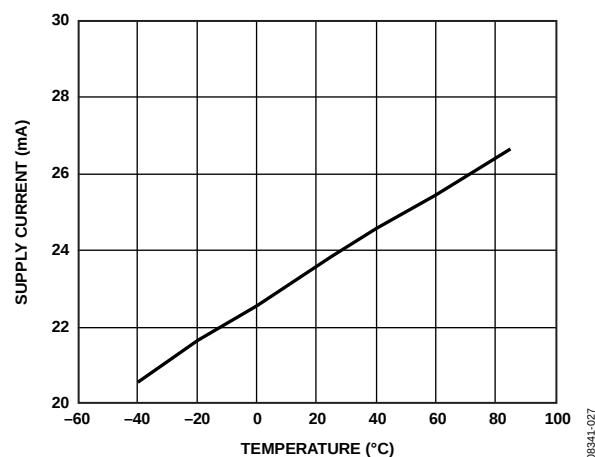


Figure 48. Supply Current vs. Temperature

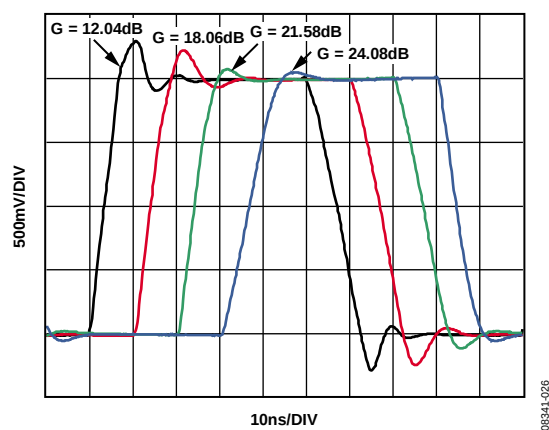


Figure 46. Large Signal Transient Response vs. Gain, $V_{OUT} = 2$ V p-p

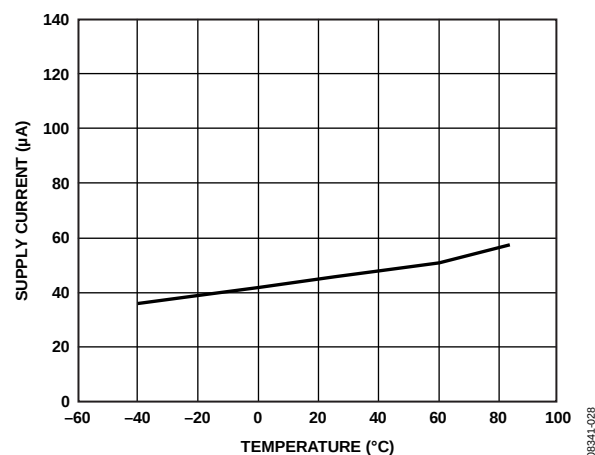


Figure 49. Supply Current vs. Temperature in Disable Mode

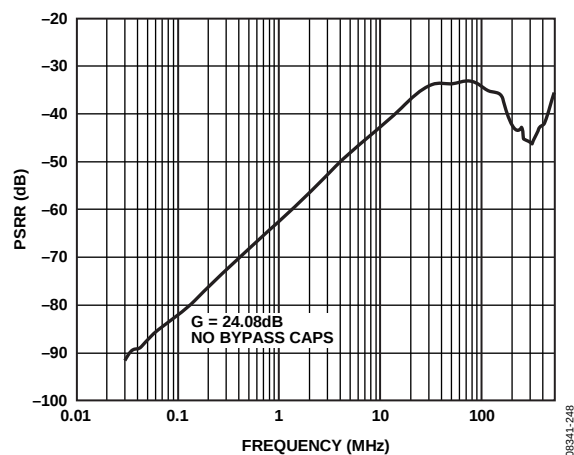


Figure 47. PSRR vs. Frequency

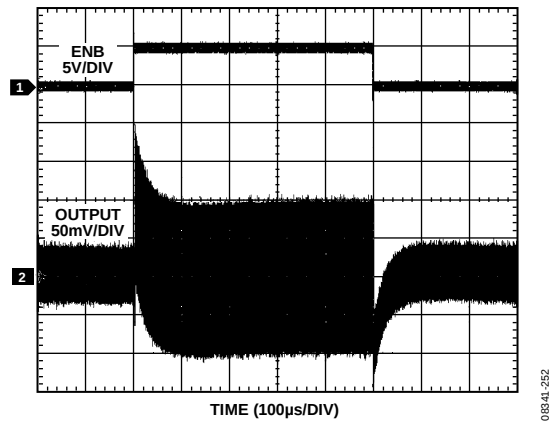


Figure 50. Small Signal Enable Response

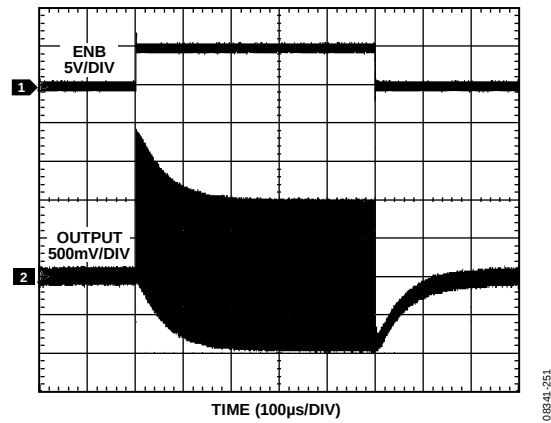


Figure 51. Large Signal Enable Response

TEST CIRCUITS

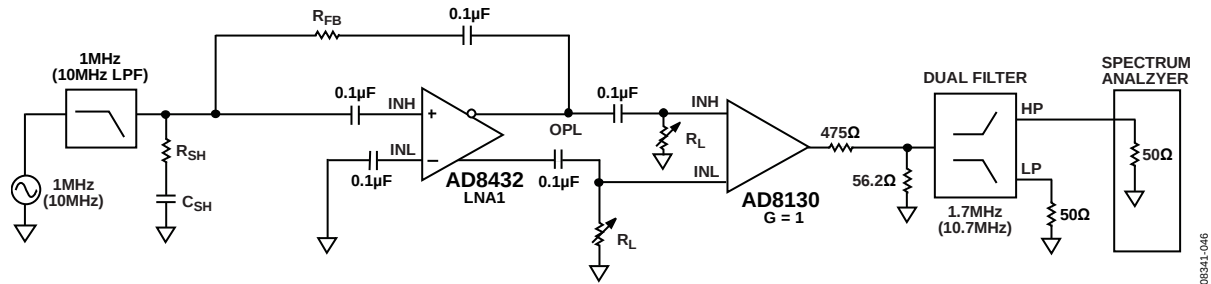


Figure 52. Harmonic Distortion vs. Resistive Load (R_L) Measurements

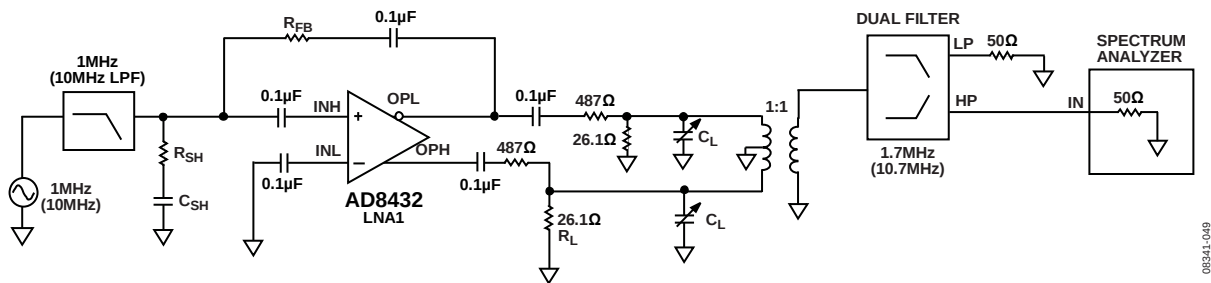


Figure 53. Harmonic Distortion vs. Capacitive Load (C_L) Measurements

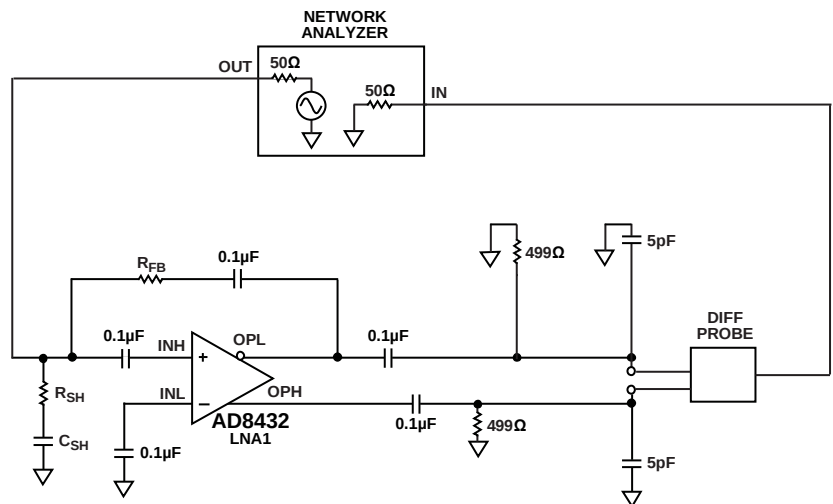


Figure 54. Frequency Response Measurements

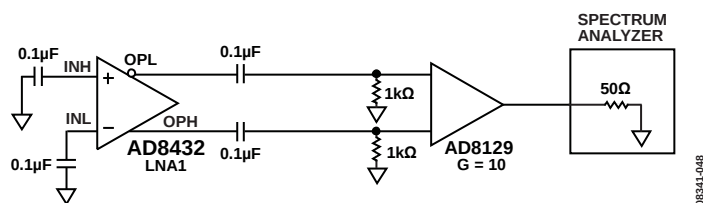


Figure 55. Voltage Noise Measurements

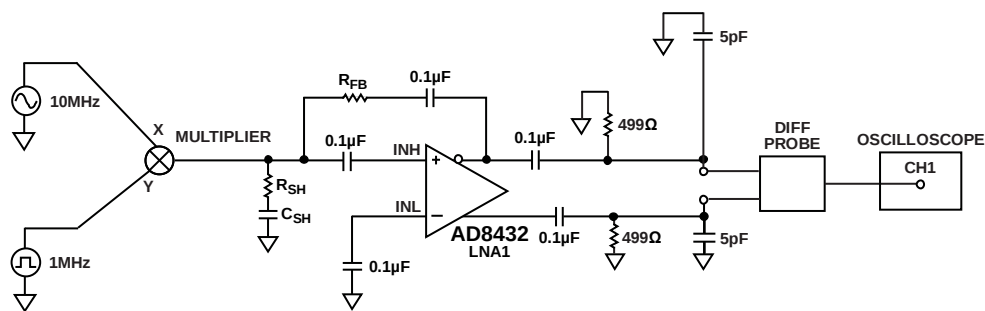


Figure 56. Overdrive Recovery Measurements

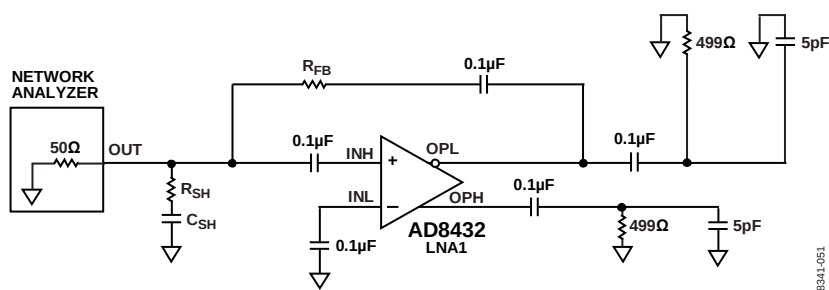


Figure 57. Input Impedance vs. Frequency Measurements

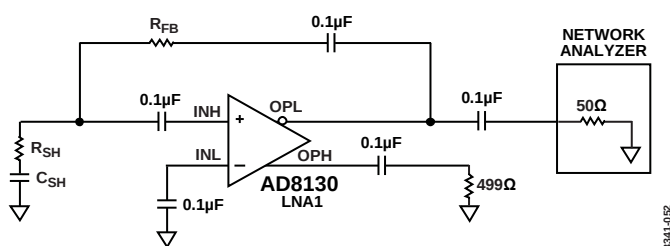


Figure 58. Output Impedance vs. Frequency Measurements

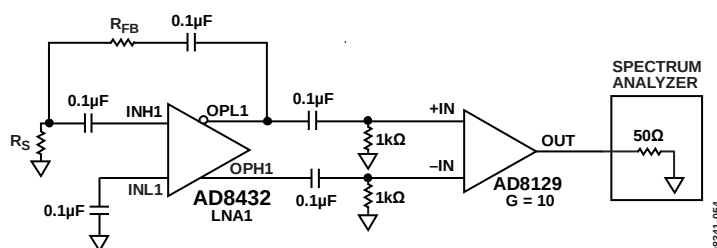


Figure 59. Noise Figure Measurements

THEORY OF OPERATION

LOW NOISE AMPLIFIER (LNA)

The AD8432 is a dual-channel, ultralow noise amplifier with integrated pin-strappable, gain-setting resistors. The resistors can be externally connected to achieve differential gains of 12.04 dB, 18.06 dB, 21.58 dB, and 24.08 dB ($\times 4$, $\times 8$, $\times 12$, and $\times 16$). A simplified schematic of a LNA is shown in Figure 60.

The LNA is driven with a single-ended input and measured differentially at the output. The inverting input INL must be ac-coupled to ground through a capacitor for proper operation. The LNA cannot be driven differentially due to the asymmetry of the internal gain setting resistors. The gain from the inverting input INL to the single-ended output (OPH or OPL) does not match the gain from the noninverting input INH to the single-ended output.

The AD8432 inputs have a dc bias voltage of 3.25 V, which is generated internally. The inputs must be ac-coupled through a series capacitor to maintain the dc bias level of the inputs. Likewise, the AD8432 outputs have a dc bias voltage of 2.5V. An ac coupling capacitor in series with each connection is recommended to prevent improper loading of the outputs.

The AD8432 supports a differential output voltage of 4.8 V p-p for the common-mode output voltage of 2.5 V. Therefore, for a differential gain $G = 12.04$ dB, the maximum input voltage allowed is 1.2 V p-p.

Clamping the inputs ensures quick recovery from large input voltages. The input back-to-back diodes, which are integrated inside the die (IND1 and IND2), should be used for the lowest gain configuration (12.04 dB) to protect the input from overdriving. They should be connected after the source resistance or before the INH coupling capacitor.

The use of a fully differential topology and negative feedback minimizes distortion. A differential signal enables smaller swings at each output, which results in reduction of third-order distortion.

The AD8432 is a voltage feedback amplifier. Due to gain bandwidth product (GBW), a decrease in bandwidth should be expected as the gain increases. Table 5 displays the values of -3 dB bandwidth for each gain with unterminated input impedance.

GAIN SETTING TECHNIQUE

Pin strapping is used to set the gain of the amplifier. Gain setting resistors are integrated in the LNA and are accessible externally through the GOH, GMH, GML, and GOL pins. By externally shorting these pins, and thereby shorting or connecting the internal resistors, the AD8432 can be configured for four different gains. Table 5 shows which pins must be connected to achieve the desired gain.

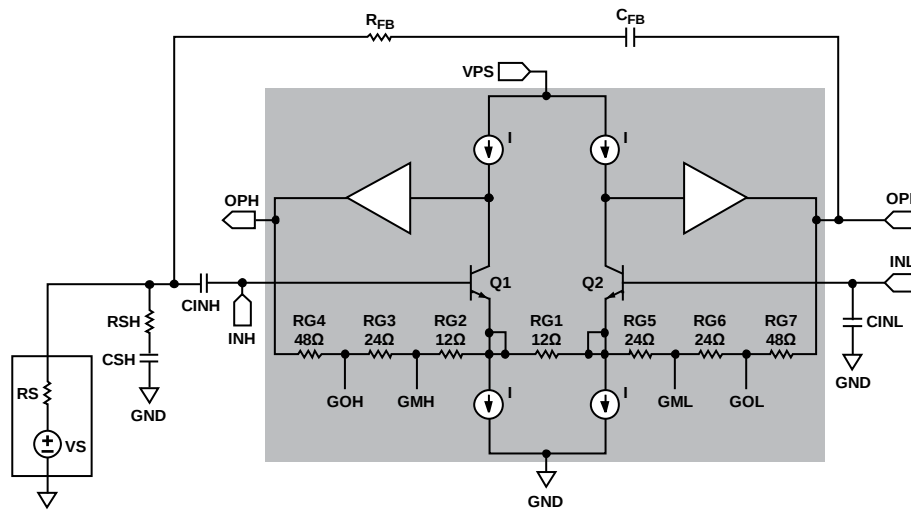


Figure 60. Simplified Schematic of LNA

Table 5. Gain Setting Using Pin-Strapping Technique and -3 dB Bandwidth for Each Gain Configuration

Differential Gain (dB)	Single Gain (dB)	-3 dB BW (MHz)	RG1 (Ω)	RG2 (Ω)	RG3 (Ω)	RG4 (Ω)	RG5 (Ω)	RG6 (Ω)	RG7 (Ω)
12.04	6.02	200	12	12	Connect GMH to GOH	Connect GOH to OPH	24	Connect GML to GOL	Connect GOL to OPL
18.06	12.04	90	12	12	24	Connect GOH to OPH	24	24	Connect GOL to OPL
21.58	15.56	50	12	12	Connect GMH to GOH	48	24	Connect GML to GOL	48
24.08	18.06	32	12	12	24	48	24	24	48

The single-ended gain from INH to OPH (see Figure 60) is defined as

$$G_{OPH-INH} = \frac{R_{G1} + R_{G2} + R_{G3} + R_{G4}}{R_{G1}}$$

The single-ended gain from INH to OPL is defined as

$$G_{OPL-INH} = -\frac{R_{G5} + R_{G6} + R_{G7}}{R_{G1}}$$

The values of the seven gain resistors were chosen so that both single-ended gains are equal. For example, to set a gain of 12.04 dB ($G = \times 4$) differentially, the gain from INH to each output (OPH, OPL) should be 6.02 dB ($G = \times 2$).

INH to OPH: For $R_{G1} = R_{G2} = R_G$, then

$$G_{OPH-INH} = \frac{R_{G1} + R_{G2}}{R_{G1}} = \frac{2 \times R_G}{R_G} = 2$$

INH to OPL: For $R_{G1} = R_G$ and $R_{G5} = 2 \times R_G$, then

$$G_{OPL-INH} = -\frac{R_{G5}}{R_{G1}} = -\frac{2 \times R_G}{R_G} = -2$$

ACTIVE INPUT RESISTANCE MATCHING

The AD8432 reduces noise and optimizes signal power transfer by using active input termination to perform signal source resistance matching.

The primary purpose of input impedance matching is to optimize the input signal power transfer. With resistive termination, the input noise increases due to the thermal noise of the terminating resistor and the increased contribution of the input voltage noise generator of the LNA. With active impedance matching, however, the contributions of both are smaller than they would be for resistive termination by a factor of $1/(1 + \frac{1}{2} \text{LNA Gain})$. The noise figure (NF) for the three terminating schemes are shown in Figure 62.

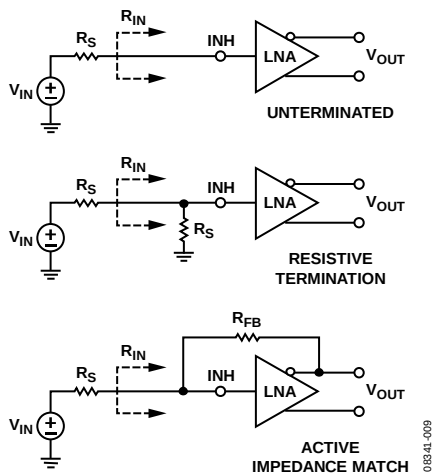


Figure 61. Input Resistance Matching

To achieve this active impedance match, connect a feedback resistor R_{FB} between the INH and OPL (see Figure 61). R_{IN} is given in Equation 1, where $G/2$ is the single-ended gain.

$$R_{IN} = \frac{R_{FB}}{1 + \frac{G}{2}} \quad (1)$$

In addition, to further reduce the input resistance, there is an internal resistance of 6.2 k Ω in parallel with the source resistance, such that

$$R_{IN} = \frac{R_{FB}}{1 + \frac{G}{2}} \parallel R_{INTERNAL} \quad (2)$$

Equation 3 should be used to calculate R_{FB} accurately for a desired input resistance and single-ended gain. Refer to Table 6 for calculated results for R_{FB} for several input resistance and gain combinations.

$$\Rightarrow R_{FB} = \frac{R_{IN} \left(1 + \frac{G}{2}\right)}{1 - \frac{R_{IN}}{R_{INTERNAL}}}, \quad R_{INTERNAL} = 6.2 \text{ k}\Omega \quad (3)$$

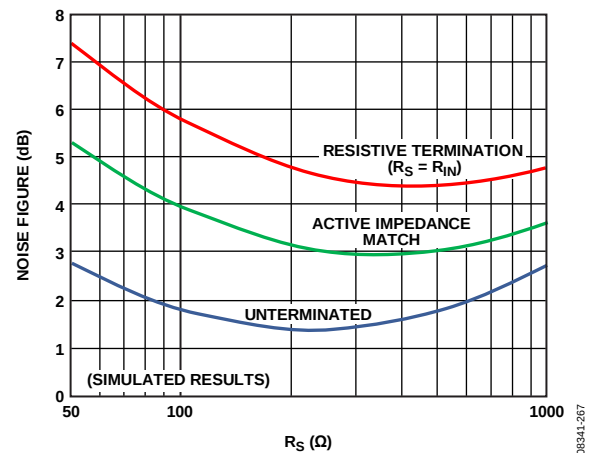


Figure 62. Noise Figure vs. R_S for Resistive, Active Match, and Unterminated Inputs

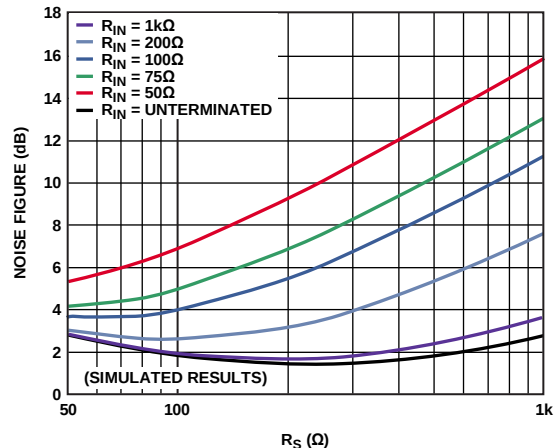


Figure 63. Noise Figure vs. R_S for Various Values of R_{IN} , Actively Matched

AD8432

The user must determine the level of matching accuracy desired and adjust R_{FB} accordingly. The R_{FB} and C_{FB} network presents a load to OPL that OPH does not see. The user may add an identical load on OPH, to improve slightly the distortion caused by this imbalance.

There is a feedback capacitor (C_{FB}) in series with R_{FB} (see Figure 60) because the dc levels of the positive output and the positive input are different. At higher frequencies, the value of the feedback capacitor needs to be considered.

The unterminated bandwidth ($R_{FB} = \infty$) is 200 MHz. The AD8432 has a low input referred voltage noise of 0.85 nV/ $\sqrt{\text{Hz}}$ at the lowest gain, 12.04 dB (unterminated configuration). To achieve such low noise, the dual amplifier consumes 24 mA, resulting in a power consumption of 120 mW.

Table 6. Feedback Resistance for Several R_{IN} and Gain Combinations

Desired R_{IN} (Ω)	Differential Gain (V/V)	Single-Ended Gain, $G/2$ (V/V)	Exact R_{FB} (Ω), Equation 2	R_{FB} (Ω), 1% Standard Value	Actual R_{IN} (Ω), Equation 2
50	4	2	151.2	150	49.6
75	4	2	227.8	226	74.4
100	4	2	304.9	301	98.7
200	4	2	620	619	199.7
1 k	4	2	3.58 k	3.57 k	998.4
50	8	4	252	250	49.6
100	8	4	508.2	511	100.5
50	12	6	352.9	357	50.6
100	12	6	711.5	715	100.5
50	16	8	453.7	453	49.9
100	16	8	914.8	909	99.4

APPLICATIONS INFORMATION

The AD8432 LNA provides precision gain and ultralow noise performance with minimal external components. Because it is a high performance part, care must be taken to ensure that it is configured optimally to attain the best performance and dynamic range for the system.

TYPICAL SETUP

The internal bias circuitry of the AD8432 sets the input bias voltage at 3.25 V and the output bias voltage at 2.5 V. It is important to ac-couple the inputs through a capacitor to maintain the internal dc bias levels. When active input termination is used (R_{FB}), a decoupling capacitor (C_{FB}) is required to isolate the input and output bias voltages of the LNA. A typical value for C_{FB} is 0.1 μF , but a smaller value capacitor is more appropriate at higher frequencies.

The unterminated input impedance of the AD8432 is 6.2 k Ω . Any input resistance between 50 Ω and 6.2 k Ω can be synthesized using active impedance matching.

At the lowest gain (12.04 dB), the gain response exhibits some peaking at higher frequencies. An RC shunt network at the input (see R_{SHx} and C_{SHx} in Figure 64) is recommended to reduce gain peaking and enhance stability at higher frequencies.

Table 7 shows the recommended values of R_{FB} , C_{SH} , and R_{SH} for all four gains and several input impedance combinations. The values for the C_{SH} and R_{SH} network are determined empirically and can be customized as needed to optimize performance. As R_{IN} increases, the value of C_{SH} diminishes, and for higher input impedance values, no capacitor may be required.

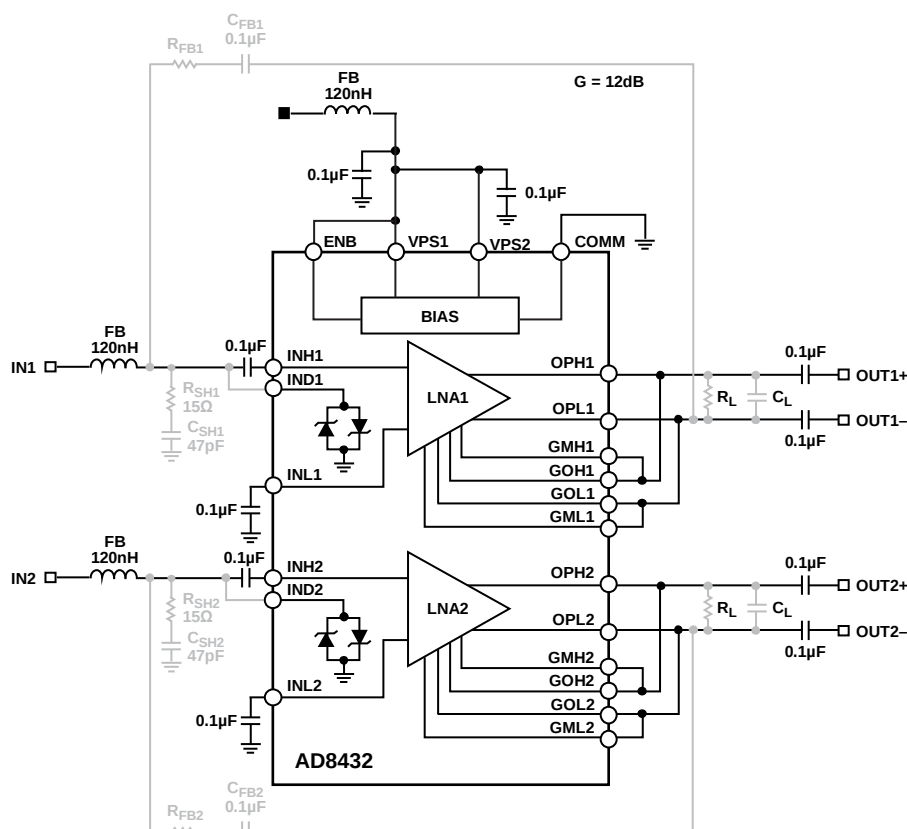


Figure 64. Typical AD8432 Setup, $G = 12.04 \text{ dB}$

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AD8432

Table 7. External Components Selections for Common Input Impedance

R_{IN} (Ω)	Gain (dB)	R_{FB} (Ω)	C_{SH} (pF)	R_{SH} (Ω)	–3 dB BW (MHz)
50	12	150	47	15	176
	18	249	30	15	116
	21	357	None	None	117
	24	453	None	None	87
75	12	226	36	15	167
	18	383	None	None	144
	21	536	None	None	100
	24	681	None	None	72
100	12	301	30	15	164
	18	511	None	None	134
	21	715	None	None	90
	24	909	None	None	63
200	12	619	18	15	164
	18	1.02 k	None	None	116
	21	1.43 k	None	None	74
	24	1.87 k	None	None	51
1 k	12	3.57 k	10	10	160
	18	5.9 k	None	None	99
	21	8.25 k	None	None	61
	24	10.7 k	None	None	43
Unterminated, $R_s = 50 \Omega$	12	∞	None	None	178
	18	∞	None	None	95
	21	∞	None	None	59
	24	∞	None	None	40
Unterminated, $R_s = 0 \Omega$	12	∞	None	None	210
	18	∞	None	None	96
	21	∞	None	None	55
	24	∞	None	None	38

I/Q DEMODULATION FRONT END

The AD8432 low noise amplifiers can be used to drive the differential RF inputs of the dual AD8333 or the quad AD8339 I/Q demodulators. The primary application for the AD8339 is phased array beamforming in medical ultrasound, specifically in CW Doppler processing. Other applications include phased array radar and smart antennas for mobile communications.

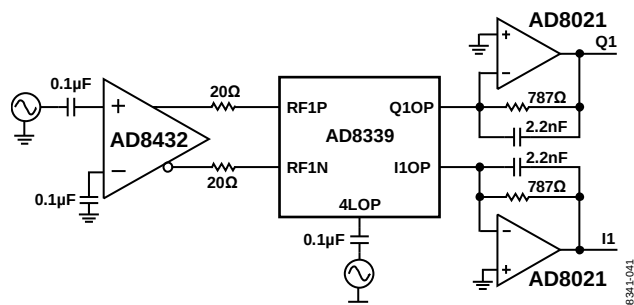


Figure 65. Block Diagram of AD8432 + AD8339 Application for Ultrasound Beamforming

Because of its low output noise and low distortion, the AD8432 ensures minimal degradation in dynamic range while amplifying the RF input signal. At the lowest gain of 12.04 dB, the AD8432 contributes only 3.4 nV/√Hz output voltage noise.

Figure 65 shows a simplified block diagram of one channel of the AD8432 driving the AD8339. The AD8432 outputs can be connected directly to the AD8339 RF inputs through 20 Ω

resistors. The 4LOP and 4LON pins of the AD8339 are driven by a differential clock signal, which has a frequency 4× that of the RF inputs. The AD8339 downconverts the RF signals, generates quadrature, and phase-shifts the resultant I and Q signals.

The I and Q outputs of the AD8339 are current outputs. A transimpedance amplifier, such as the AD8021, processes the outputs and performs several functions, including the following:

- Current-to-voltage conversion
- Summation amplifier for multiple channels
- Active low-pass filter

In beamforming applications, the I and Q outputs of a number of receiver channels are summed, which increases the system dynamic range by $10 \log_{10}(N)$, N being the number of channels being summed. The external RC feedback network of the AD8021 is a 100 kHz low-pass filter as shown in Figure 65. Refer to the AD8333 and AD8339 datasheets for more details on implementing I/Q demodulators.

Evaluation boards are available for the AD8432 and the AD8339 to facilitate system level design and test. A detailed reference schematic of the setup is shown in Figure 66. The AD8432 is shown in this configuration with a gain of 12.04 dB, with unterminated inputs. If active termination is preferred, use an R_{FB} and C_{FB} network as discussed in the Theory of Operation. Clamping diodes IND1/IND2 can be connected to IN1/IN2 to protect the LNA input from being overdriven.

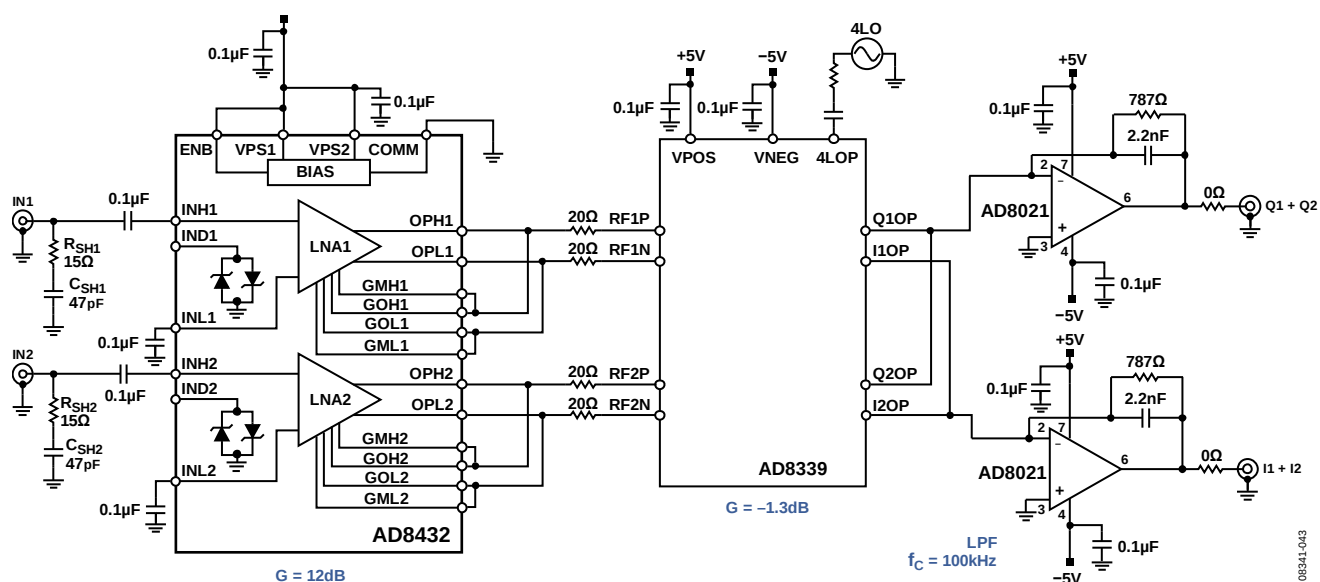


Figure 66. Schematic of AD8432 (G = 12.04 dB) + AD8339 Application for Ultrasound Beamforming

DIFFERENTIAL-TO-SINGLE-ENDED CONVERSION

Some applications require the low noise and high dynamic range of the AD8432; however, they may also require a single-ended output, rather than a differential output. The [AD8129](#) and [AD8130](#) differential receiver amplifier can be used for the differential-to-single-ended conversion of the AD8432 output, as shown in Figure 67.

The AD8129 is a low noise, high gain (10 or greater) amplifier intended for applications over very long cables, where signal attenuation is significant. The AD8130 is stable at a gain of 1 and can be used for applications where lower gains are required. The AD8129 and AD8130 have user-adjustable gain, set by the ratio of two resistors, to help compensate for losses in the transmission line.

A transformer or balun can also be used to convert the differential output of the AD8432 to a single-ended output. Transformers have lower distortion; however, care must be taken to properly match the impedance of the transformer. The test circuit for distortion measurements in Figure 53 uses an ADTT1-1 transformer to perform differential-to-single-ended conversion.

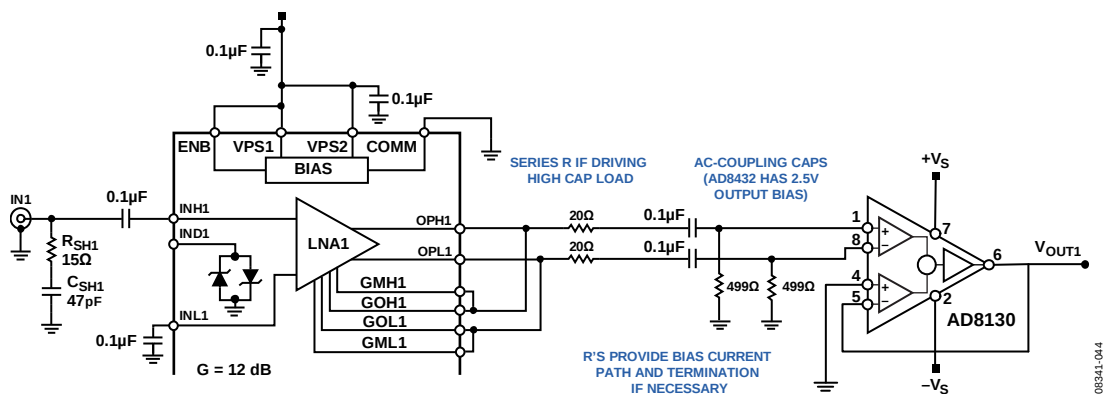


Figure 67. AD8432 Differential-to-Single-Ended Conversion Using the AD8129/AD8130 with Unity Gain

EVALUATION BOARD

Figure 68 shows the AD8432 evaluation board, and the schematic diagram is shown in Figure 69. Using the board is a convenient and fast way to verify system design and assess the performance of the AD8432 under the user-specific operating conditions. The board provides access to all LNA inputs, outputs, and gain setting pins. The board is shipped in a typical $G = 12.04\text{ dB}$ configuration but is designed to allow customization of the setup as required.

The AD8432-EVALZ requires a single 5 V power supply. An on-board switch (S1) allows VPS to drive the enable (ENB) input.

GAIN SETTING

Headers (W5 to W12) are provided across the gain setting pins and can be shorted using jumpers to allow gain setting quickly and easily. Alternately, it is recommended to short the gain setting pins using surface-mount (0402), $0\ \Omega$ resistors (R1 to R4, R9 to R12) that eliminate the small parasitic capacitances from longer trace lengths to the headers. As shipped, the evaluation board is configured for $G = 12.04\text{ dB}$ with these $0\ \Omega$ resistors.

Table 8 outlines which resistors or headers need to be installed or shorted for each gain configuration.

Table 8. Gain Setting Using Resistors or Headers

LNA1		LNA2		Gain (V/V)			
				4	8	12	16
R1	W5	R9	W9	X ¹	X ¹		
R2	W6	R10	W10	X ¹		X ¹	
R3	W7	R11	W11	X ¹		X ¹	
R4	W8	R12	W12	X ¹	X ¹		

¹ X = shorting the indicated header or resistor.

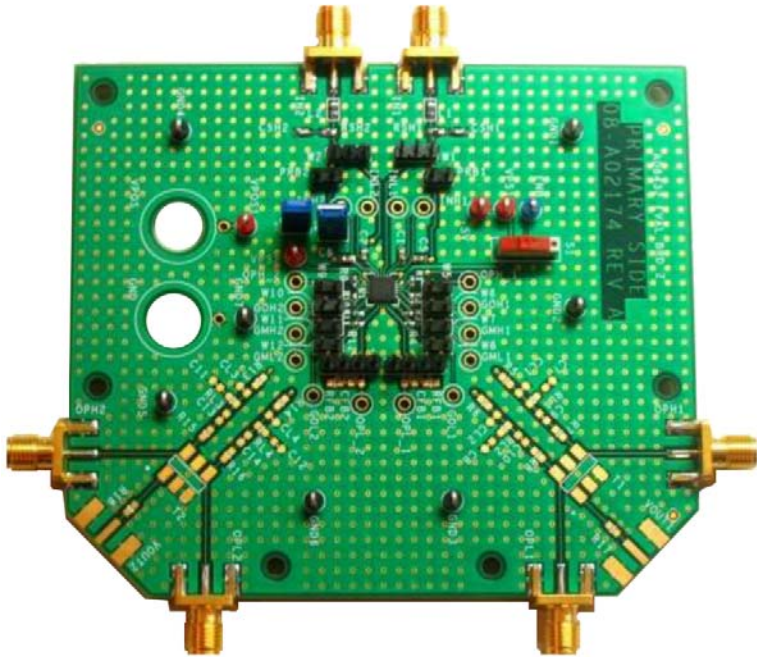


Figure 68. Evaluation Board

08341-0-5

AD8432

SCHEMATIC

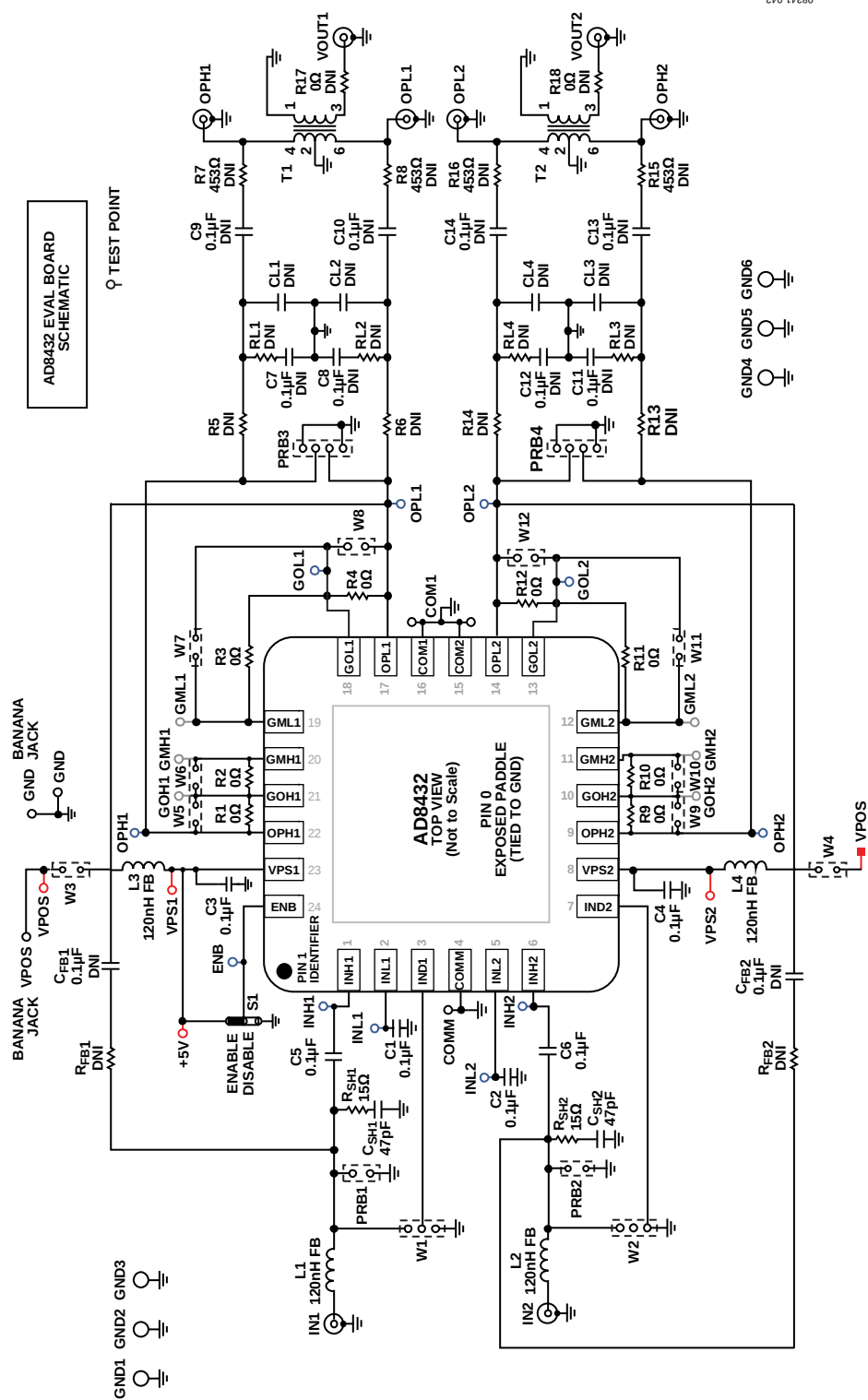


Figure 69. Schematic

POWER SUPPLY

The AD8432 should be powered by a single 5 V supply connected to the VPOS terminal. Separate supplies can be used for VPS1, VPS2, and ENB, or they can all be tied to VPOS by shorting the W3 and W4 headers and the S1 switch. Ferrite beads and decoupling capacitors are installed for isolation, protection, and power supply noise reduction.

INPUT TERMINATION

Active input impedance matching can be realized by installing a feedback resistor (R_{FB}), the value of which is determined by the gain and source impedance, as described in the Theory of Operation section. C_{FB} provides the necessary ac coupling between the input and output when using active termination; a 0.1 μ F capacitor value is recommended. The R_{FB} and C_{FB} network presents a load to OPL, and an equivalent load at OPH can be used to balance the differential output.

Input clamping diodes (IND1 and IND2) can be connected to the inputs, by shorting the connection on the W1 and W2 headers. The diodes provide overvoltage protection to the input and enable faster overdrive recovery times, especially at the lowest gain (12.04 dB).

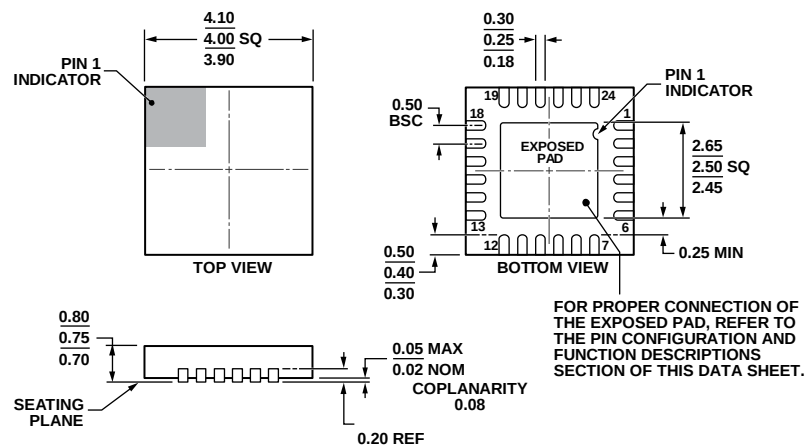
OUTPUT

The AD8432 evaluation board provides the space to configure the output loading conditions required by the user, by populating the given footprints (for example, RL1, RL2, C7, and C8). SMA connectors are available at the outputs, and space for a transformer is also available for differential-to-single-ended conversion.

The 4-pin headers, PRB3 and PRB4, are placed close to the AD8432, and they provide a way for monitoring the differential output or the single-ended output using a high impedance differential probe. The two inner pins of the headers are connected to OPL/OPH, and the two outer pins of the headers are connected to ground.

There are several footprints provided to install ac coupling capacitors at the outputs (C7 to C14). The AD8432 outputs are biased internally at 2.5 V. To maintain the dc bias level, use coupling capacitors between the outputs and the load.

OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MO-220-WGGD.

Figure 70. 24-Lead Lead Frame Chip Scale Package [LFSCP_WQ]
4 mm × 4 mm, Very Very Thin Quad
(CP-24-7)
Dimensions shown in millimeters

ORDERING GUIDE

Model	Temperature Range	Package Description	Package Option
AD8432ACPZ-R7 ¹	−40°C to +85°C	24-Lead LFCSP_WQ, 7" Tape and Reel	CP-24-7
AD8432ACPZ-RL ¹	−40°C to +85°C	24-Lead LFCSP_WQ, 13" Tape and Reel	CP-24-7
AD8432ACPZ-WP ¹	−40°C to +85°C	24-Lead LFCSP_WQ, Waffle Pack	CP-24-7
AD8432-EVALZ ¹		Evaluation Board	

¹ Z = RoHS Compliant Part.